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Chirality analysis of horizontally aligned single-walled carbon nanotubes: decoupling populations and lengths†

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Utilizing the aligned morphology of single-walled carbon nanotubes (SWCNTs) grown on crystal quartz substrates together with systematic Raman mapping measurements, the populations and lengths of SWCNTs with different chiralities (n,m) were independently evaluated. Chiralities of SWCNTs were assigned on a one-by-one basis by comparing radial breathing mode frequencies with the Kataura plot. The SWCNT lengths were determined by Raman mapping and/or scanning electron microscopy. Both the populations and lengths of the SWCNTs grown in this study with a diameter of 1.14 to 1.29 nm showed no clear dependence on their chiral angles.

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Introduction

The atomic configurations of single-walled carbon nanotubes (SWCNTs)¹ are typically represented by two integers (n,m), signifying the chirality, since the electrical and optical properties of SWCNTs differ depending on chirality.^{2,3} While as-grown SWCNT ensembles are generally composed of SWCNTs with various chiralities, specific SWCNTs possessing appropriate properties are required for electrical and optical applications. Although separation techniques to obtain chirality-specific SWCNTs from as-grown samples have been developed,^{4,5} direct growth of chirality-controlled SWCNTs is still highly desirable.

The chiral index (n,m) is equivalent to the pair of the diameter and chiral angle of the SWCNTs. Control of the SWCNT diameter is possible, to a certain extent, *via* tuning the diameter of catalytic nanoparticles during the chemical vapour deposition (CVD) growth process.⁶ Various growth conditions and characterization methods have demonstrated the chirality-controlled growth of SWCNTs and have shown that the abundance of chiral SWCNTs with larger chiral angles is high,^{7–15} although the origin of this near-armchair preference is the subject of theoretical discussion.^{16–18} During the CVD growth of SWCNTs, carbon cap structures are generated on catalyst nanoparticles, followed by lifting off to elongate the structures into tubes.^{19,20} The measured abundance of SWCNTs with a given chirality is determined by taking the product of the population and average length of each specific type. Since the

energetic stability of the cap structure on the catalyst exhibits a dependence on chirality,^{8,16} it is possible that cap structures corresponding to certain chiralities are preferentially nucleated, which biases the formation of SWCNT populations of different chiralities. In contrast, the screw dislocation model suggests that chiral SWCNTs with larger chiral angles have higher growth rates,¹⁷ resulting in longer average lengths for near-armchair SWCNTs. The chiral angle dependence of SWCNT growth rates has been studied by *in situ* Raman measurements of single SWCNT²¹ and SWCNT growth from chirality-separated SWCNT seeds.²² As well, a theoretical model of SWCNT abundance considering both nucleation probability and growth rates has been reported.¹⁸ Despite these efforts, an experimental analysis of the detailed chirality distribution is still required to obtain an improved understanding of chirality-controlled growth.

Since conventional methods used to determine SWCNT chirality distribution cannot distinguish between the contributions of population and length, novel methods to analyse chirality in detail are needed. As an example, spectroscopic evaluation of ensemble SWCNT samples, including SWCNT dispersions in solvent and SWCNT network films, yields chirality abundance data that reflect both populations and lengths.^{7–9,14} In order to investigate SWCNT structures on a one-by-one basis, it is necessary to isolate the SWCNTs. Studies of isolated SWCNTs, however, do not give SWCNT populations as long as the measurements are performed in a random manner.^{10,11,13,23} This occurs because longer SWCNTs tend to appear more frequently in the detection area, and so the count of certain chiralities is affected by both populations and lengths simultaneously. Compared with randomly oriented SWCNTs, aligned SWCNTs lying on substrates represent better candidates for systematic measurements, and SWCNTs both isolated and aligned on substrates have been grown using crystalline substrates²⁴ or laminar gas-flow.²⁵ Although the chirality

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distributions of horizontally aligned SWCNTs have been studied,^{12,15,26,27} there have been no reports on the independent evaluation of the chirality dependence of both population and length.

In this study, we evaluated SWCNTs by utilizing a horizontally aligned morphology in conjunction with Raman mapping measurements. In this manner, a detailed chirality distribution of SWCNTs was obtained by independently investigating populations and lengths.

Experimental method

Horizontally aligned SWCNTs were grown on crystal quartz substrates using an alcohol CVD method.²⁸ By tuning the growth conditions described in detail in our previous reports,^{29,30} SWCNTs with moderate densities were prepared. Briefly, the growth procedure employed ethanol vapour (partial pressure ~ 30 Pa) together with an Ar/H₂ (3%) gas mixture at 750 °C for 15 min, using an Fe catalyst patterned by photolithography and vacuum deposition (nominal thickness ~ 0.2 nm). To avoid the Raman signal of the crystal quartz substrate, horizontally aligned SWCNTs were subsequently transferred onto SiO₂/Si substrates using poly(methyl methacrylate) films.³¹ Marker structures were fabricated by photolithography, sputter deposition of Ti, and lift-off to confirm the measurement positions under the optical microscope associated with the Raman measurement system. Raman spectra of fabricated samples were obtained using a Raman spectrometer (Renishaw, inVia) with four excitation wavelengths: 488 nm (2.54 eV), 532 nm (2.33 eV), 633 nm (1.96 eV), and 785 nm (1.58 eV). In particular, high-resolution Raman mapping measurements were performed with the excitation at 488 nm. The polarization angle of the excitation laser was adjusted such that it was parallel to the alignment direction of the SWCNTs. The streamline-shaped laser spot was 0.8 μm wide and 20 μm long, with an intensity of ~ 10 mW (power density ~ 0.6 mW μm^{-2}). The acquisition time for one spectrum ranged from 60 to 90 s and the mapping resolution was 0.6 μm in the SWCNT alignment direction and 0.2 μm in the direction perpendicular to the alignment. Raman shifts were calibrated using sulfur as a reference. Radial breathing mode (RBM) peaks were fitted with a Lorentz function to determine the RBM frequencies (ω_{RBM}) and the chiralities of the SWCNTs were assigned based on these ω_{RBM} values together with the excitation energy,²³ employing Kataura plots.^{32,33} The lengths of SWCNTs were determined from Raman mapping images and/or by scanning electron microscopy (SEM, Hitachi, S-4800).

Results and discussion

Fig. 1a shows a SEM image of the horizontally aligned SWCNTs as well as the metal markers on a SiO₂/Si substrate. In this image, SWCNTs with moderate densities (~ 2 tubes per μm near the catalyst pattern) are observed. Raman measurements were performed at the four excitation wavelengths, and the resulting spectra and ω_{RBM} distributions are presented in Fig. 1b and c. The ω_{RBM} values, ranging from 100 to 260 cm^{-1} , indicate that

the SWCNTs were approximately 0.9–2.0 nm in diameter, including both metallic and semiconducting SWCNTs. The chiralities of the larger diameter SWCNTs were difficult to assign because their ω_{RBM} values were quite close to one another in the low frequency region of the Kataura plot. In this report, when assessing the diameter distributions of the SWCNTs, we considered it appropriate to use the ω_{RBM} values in the range of 180–212 cm^{-1} , obtained with the excitation at 488 nm, for chirality assignment.

The samples were carefully investigated by Raman mapping measurements with a 488 nm excitation wavelength. Measurements were conducted over rectangular areas ~ 15 μm wide in the SWCNT alignment direction and totally ~ 320 μm wide in the perpendicular direction, including the catalyst patterned area in which the SWCNT growth had begun at the centre of the rectangle. These regions contain more than ~ 1200 aligned SWCNTs, and 82 RBM peaks with ω_{RBM} values ranging from 180 to 212 cm^{-1} were obtained. The well-organized morphology of the horizontally aligned SWCNTs and the systematic measurement process enabled us to investigate all resonant SWCNTs grown from the catalyst area to the alignment area without multiple counting. Fig. 2a shows typical RBM spectra of a SWCNT acquired at five different points along the tube axis. A ω_{RBM} deviation of less than ± 1 cm^{-1} was observed along a nanotube. Fig. 2b presents a SEM image superimposed over Raman mapping that shows the G-band intensities of the aligned SWCNTs. Here the ω_{RBM} values of the SWCNTs are indicated by arrows. The RBM spectra in Fig. 2a correspond to the SWCNT circled in blue in Fig. 2b. Lengths of SWCNTs were determined by Raman mapping and SEM observation. When entire SWCNTs fell within Raman mapping areas, SWCNT

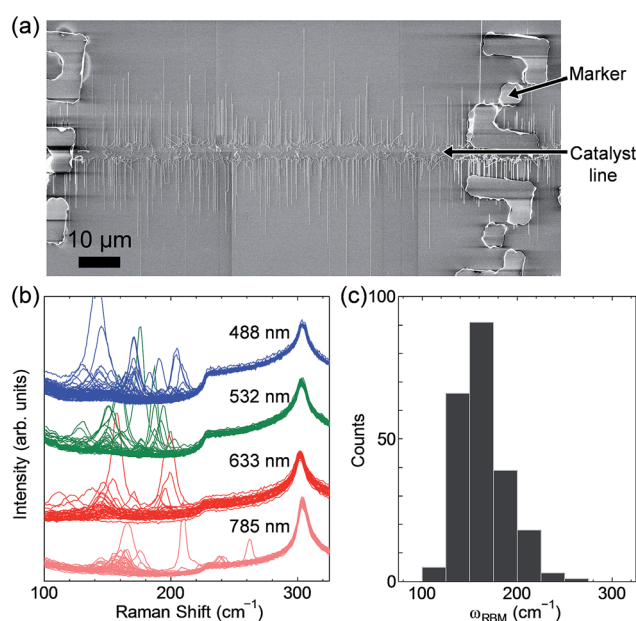


Fig. 1 (a) SEM image of horizontally aligned SWCNTs and marker structures on a SiO₂/Si substrate. The image is composed of multiple SEM images. (b) Raman spectra of aligned SWCNTs. Excitation wavelengths are 488, 532, 633, and 785 nm. (c) Distribution of RBM frequencies.



lengths were determined solely by Raman mapping by investigating the successive appearance of RBM peaks with similar ω_{RBM} values. When the SWCNTs extended beyond the Raman mapping area, the lengths were determined by referring to SEM observations. In this case, the SWCNT density at the edges of Raman mapping areas is much lower than that near the catalyst pattern, and thus we can unambiguously find one corresponding SWCNT in SEM images by comparing Raman mapping images and SEM images. Further details of length determination are shown in Fig. S1 in the ESI.† According to these procedures, we obtained both the ω_{RBM} values and the lengths of individual SWCNTs.

Fig. 3a shows the acquired ω_{RBM} values together with Kataura plots,³³ while Fig. 3b provides the ω_{RBM} distribution. Several Kataura plots have been reported in previous studies.^{33–37} The Kataura plots employed here were originally constructed by the fitting of experimental ω_{RBM} values of vertically aligned SWCNTs obtained with a tunable laser excitation wavelength.³³ As shown in Fig. 3a and b, the ω_{RBM} values are clearly divided into five distinct regions, believed to correspond to the family for which $2n + m = 29$, including (10,9), (11,7), (12,5), (13,3), and (14,1). These chiralities exhibit third interband transition energies (E_{33}^{S}) of 2.56–2.62 eV, values of which are within 0.1 eV of the excitation energy of 2.54 eV (488 nm). The (12,7) chirality is also regarded as a possible candidate since its ω_{RBM} value is approximately 183 cm^{-1} ; however, its E_{33}^{S} of 2.71 eV is too far from the excitation energy. Additionally, the family for which $2n + m = 32$, having E_{33}^{S} values of 2.42–2.44 eV, is an alternative choice for the ω_{RBM} range of 180–195 cm^{-1} . To confirm these assignments, we investigated the same area of the sample by Raman measurements using a 532 nm excitation wavelength. In this case, corresponding RBM peaks were not found in the range of 180–195 cm^{-1} at the points where peaks had appeared in response to the 488 nm excitation. Thus, we excluded the possibility that the peaks in the range of 180–195 cm^{-1} resulting from the 488 nm excitation were from the $2n + m = 32$ family. We therefore assigned the SWCNTs with ω_{RBM} values of 180.9–184.2, 190.0–193.1, 197.4–200.7, 202.5–205.2, and 207.7–211.7 to chiralities (10,9), (11,7), (12,5),

(13,3), and (14,1), respectively. The ω_{RBM} values of SWCNTs of a given chirality were found to vary by approximately $\pm 2 \text{ cm}^{-1}$, likely as a result of variations in the environmental conditions of the SWCNTs. The ω_{RBM} values of SWCNTs are known to be affected by interactions with the surrounding environment,³⁵ including underlying substrates,³⁸ other SWCNTs forming bundles,^{39,40} and adsorbed water molecules.^{40,41} The ω_{RBM} values were plotted against the diameter of assigned chiralities in comparison with the previous reports (Fig. S2†). We note that the assigned five chiralities do not represent all of the grown chiralities, but we focused on the chiralities due to measurement limitations.

Subsequently, the chiral angle dependence of the SWCNT growth was assessed using the obtained chirality-resolved SWCNT populations. Although the assigned five species of SWCNTs had different diameters as well as chiral angles, we considered that their diameter range of 1.14–1.29 nm was sufficiently small so as to have a minimal effect on the SWCNT growth. The SWCNT populations of specific chiralities were thus plotted against the chiral angles (Fig. 4a). These data show a relatively small population of the (10,9) SWCNTs, presumably due to the chirality dependence of the RBM intensity, since the RBM intensity is known to be weaker for SWCNTs with larger diameters and larger chiral angles.⁴² It is reasonable to assume that the RBM intensity did not affect the measurement results in this study because the Raman spectra of individual SWCNTs were acquired and the number of RBM peaks was counted on a one-by-one basis. However, we cannot exclude the possibility that RBM peaks weaker than the threshold value that was used to assess the presence of peaks were neglected. Fig. S3† shows the RBM intensity, normalized by the Si peak intensity at ~ 303

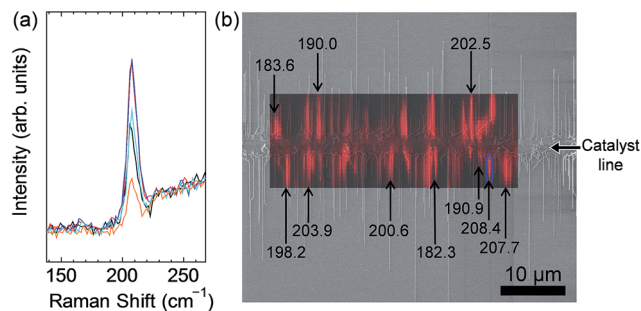


Fig. 2 (a) Raman spectra of the same SWCNT measured at different five points along its axis. Excitation wavelength is 488 nm. (b) Superimposed SEM and Raman mapping images. The red contrast of the Raman mapping image shows the G-band intensity obtained with a 488 nm excitation. The values indicated by arrows are the RBM frequencies (cm^{-1}) of the SWCNTs. Raman spectra shown in (a) are from the SWCNT in the blue circle.

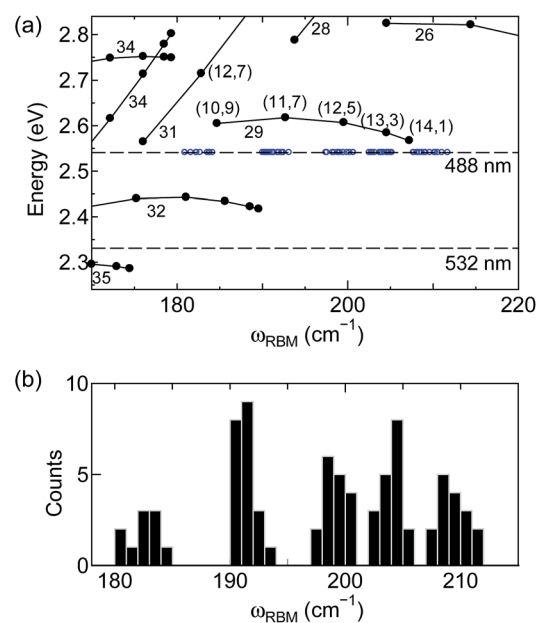


Fig. 3 (a) Transition energies versus RBM frequencies. Blue open circles are acquired values from individual SWCNTs with a 488 nm excitation. Black dots are calculated Kataura plots.³³ Chiral indices (n,m) and $2n + m$ family numbers are denoted. (b) Distribution of RBM frequencies for 82 different SWCNTs.



cm^{-1} , as a function of ω_{RBM} . A comparison of the RBM intensities at different wavenumbers demonstrates that the intensity tends to be stronger in the higher wavenumber regions. We believe that all the SWCNTs, with the exception of the (10,9) species, had sufficient peak intensity and thus all the SWCNT chiralities were observed. Therefore the populations derived for the SWCNTs grown in this study are considered to have been unbiased by chiral angles.

We then investigated the effect of the chiral angle on SWCNT lengths. Fig. 4b shows the average lengths of SWCNTs having different chiralities as functions of the chiral angle. Here, the average SWCNT length over the five chiralities was in the range of 3–4 μm . This result indicates that the chiral angle did not have a pronounced effect on the SWCNT lengths under the present growth conditions. These findings are important since the evaluation of the lengths of chirality-resolved SWCNTs is difficult using conventional methods, and there have been only a few reports of such evaluations to date.^{22,43}

The data herein demonstrate that both the populations and lengths of SWCNTs exhibit no clear dependence on the chiral angle. We consider that the growth of SWCNTs with a diameter of 1.14–1.29 nm in this study was unaffected by the chiral angle. This is in accordance with previous reports which showed that SWCNTs with a relatively large diameter ($> \sim 1.0$ nm) have no chiral angle dependence.^{8,9,44,45} Additionally, the growth of SWCNTs from SWCNT seeds of specific chiralities has shown that SWCNTs with larger chiral angles exhibit higher growth rates but shorter growth lifetimes, resulting in no clear dependence of the final SWCNT lengths on chirality.²² It is possible that the SWCNT growth in this study had a similar tendency, and accordingly chiral angle dependence was not directly observed for the SWCNT lengths.

Due to the restricted Raman resonance conditions and the difficulty in assigning larger diameter SWCNTs, the number of assigned chiralities in the present study was limited. However, the data did indicate a relatively flat distribution of populations and uniformity in the lengths of SWCNTs with several different chiralities, which is otherwise difficult to acquire by conventional measurement methods. The application of this technique to SWCNTs obtained under other growth conditions should enable a more detailed study of chirality-controlled SWCNT growth.

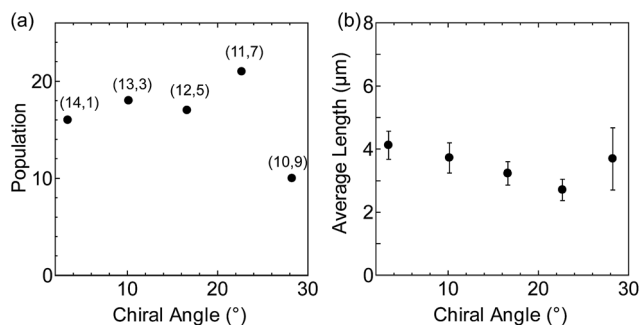


Fig. 4 (a) Populations and (b) average lengths of SWCNTs of five different chiralities plotted against the chiral angle.

Conclusions

We examined the chiralities of SWCNTs by Raman mapping measurements of horizontally aligned SWCNTs. Through analysing the chirality of individual SWCNTs, we independently evaluated both the populations and lengths of five chiralities in the $2n + m = 29$ family. Neither the chirality-resolved populations nor the lengths of the SWCNTs showed a clear dependence on the chiral angle. This measurement strategy will assist in the future elucidation of the mechanism of the structure-controlled growth of SWCNTs.

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